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Title: Advanced techniques in RF Power Amplifier design. (The Book End)

Author(s): Dan Masse .

Source: Microwave Journal.

Document Type: Book review , Brief article

Article Preview :

Steve C. Cripps Artech House Inc. 320 pages; \$99, [pounds sterling]69 ISBN: 1-58053-282-9 By the author's own admission, this book is a sequel to his previous publication RF Power Amplifiers for Wireless Communications (Artech House Inc., 1999). It offers a more in-depth understanding of the theory of RF power amplifiers and covers some topics that were barely mentioned previously, such as bipolar junction transistors (BJT) and others that deserve a more detailed treatment. With the advent of heterojunction bipolar transistor (HBT) and silicon germanium (SiGe) technology, interest in these...

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